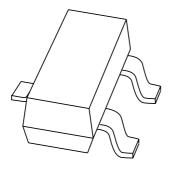
DISCRETE SEMICONDUCTORS

DATA SHEET



BAP64-05 Silicon PIN diode

Product specification Supersedes data of 1999 Jul 01 1999 Aug 19





Silicon PIN diode BAP64-05

FEATURES

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz.

APPLICATIONS

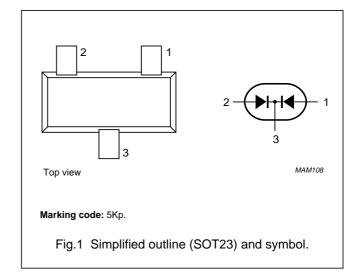
• RF attenuators and switches.

DESCRIPTION

Two planar PIN diodes in common cathode configuration in a SOT23 small plastic SMD package.

PINNING

PIN	DESCRIPTION	
1	anode (a1)	
2	anode (a2)	
3	common cathode	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V _R	continuous reverse voltage		_	175	V
I _F	continuous forward current		_	100	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

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ELECTRICAL CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
Per diode					
V _F	forward voltage	I _F = 50 mA	0.95	1.1	V
I _R	reverse current	V _R = 175 V	_	10	μΑ
		V _R = 20 V	_	1	μΑ
C _d	diode capacitance	V _R = 0; f = 1 MHz	0.52	_	pF
		V _R = 1 V; f = 1 MHz	0.37	_	pF
		V _R = 20 V; f = 1 MHz	0.23	0.35	pF
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	20	40	Ω
		I _F = 1 mA; f = 100 MHz; note 1	10	20	Ω
		I _F = 10 mA; f = 100 MHz; note 1	2	3.8	Ω
		I _F = 100 mA; f = 100 MHz; note 1	0.7	1.35	Ω
τ∟	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	1.55	-	μs
L _S	series inductance		1.4	_	nH

Note

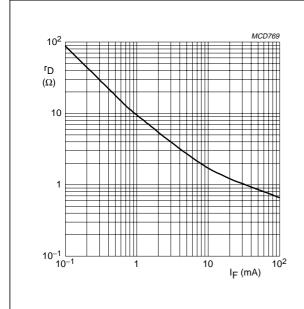
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point		K/W

^{1.} Guaranteed on AQL basis: inspection level S4, AQL 1.0.

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GRAPHICAL DATA



f = 100 MHz; $T_i = 25 \,^{\circ}\text{C}$.

Fig.2 Forward resistance as a function of forward current; typical values.

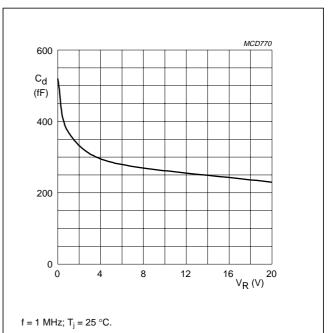
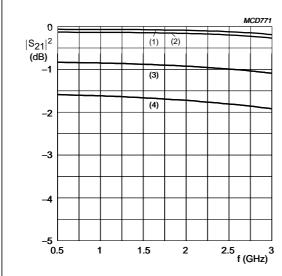


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

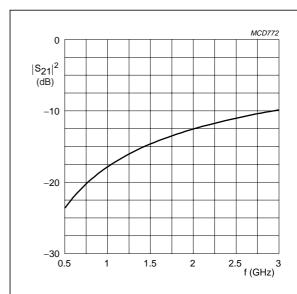


- (1) $I_F = 100 \text{ mA}.$
- (3) $I_F = 1 \text{ mA}.$
- (2) $I_F = 10 \text{ mA}.$
- (4) $I_F = 0.5 \text{ mA}.$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network.

 $T_{amb} = 25 \, ^{\circ}C.$

Fig.4 Insertion loss ($|S_{21}|^2$) of the diode as a function of frequency; typical values.



Diode zero biased and inserted in series with a 50 Ω stripline circuit. T_{amb} = 25 $^{\circ}C.$

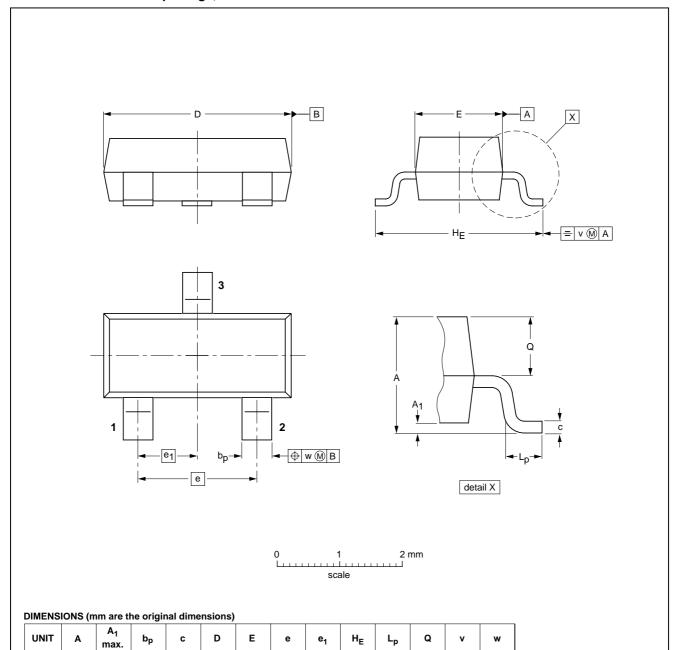
Fig.5 Isolation ($|S_{21}|^2$) of the diode as a function of frequency; typical values.

Silicon PIN diode BAP64-05

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT23					97-02-28

0.95

2.5 2.1 0.45 0.15 0.55 0.45

0.2

0.1

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0.48

0.38

0.15 0.09 3.0 2.8 1.4 1.2

1.9

1.1 0.9

mm

0.1

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DEFINITIONS

Data sheet status			
Objective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification This data sheet contains preliminary data; supplementary data may be published late			
Product specification This data sheet contains final product specifications.			
Limiting values			
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information			

LIFE SUPPORT APPLICATIONS

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Where application information is given, it is advisory and does not form part of the specification.

Silicon PIN diode BAP64-05

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